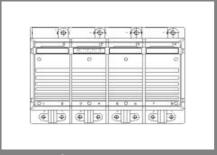
SKiiP 1092GB170-4D



SKiiP[®] 2

2-pack - integrated intelligent Power System

Power section

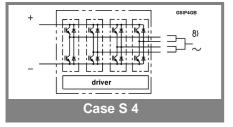
SKiiP 1092GB170-4D

Features

- SKiiP technology inside
- CAL diode technology
- · Integrated current sensor
- Integrated temperature sensor
- Integrated heat sink
- IEC 60721-3-3 (humidity) class 3K3/IE32 (SKiiP[®] 2 System)
- IEC 60068-1 (climate) 40/125/56
- UL recognized file no. E63532
- with assembly of suitable MKP capacitor per terminal (SEMIKRON type is recommended)
- 8) AC connection busbars must be connected by user, copper busbars available on request

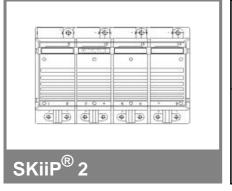
| Absolute | Maximum Ratings | Γ _s = 25 °C unless otherwise specified | | | | |
|-------------------------------------|---|---|-------|--|--|--|
| Symbol | Conditions | Values | Units | | | |
| IGBT | | | | | | |
| V_{CES} | | 1700 | V | | | |
| V _{CES} V _{CC} 1) | Operating DC link voltage | 1200 | V | | | |
| V_{GES} | | ± 20 | V | | | |
| I _C | T _s = 25 (70) °C | 1000 (750) | Α | | | |
| Inverse diode | | | | | | |
| $I_F = -I_C$ | T _s = 25 (70) °C | 1000 (750) | Α | | | |
| I _{FSM} | $T_i = 150 ^{\circ}\text{C}, t_p = 10 \text{ms}; \text{sin}.$ | 8640 | Α | | | |
| I²t (Diode) | Diode, T _j = 150 °C, 10 ms | 373 | kA²s | | | |
| T_j , (T_{stg}) | | - 40 (- 25) + 150 (125) | °C | | | |
| V _{isol} | AC, 1 min. (mainterminals to heat sink) | 4000 | V | | | |

| Characteristics T _s = 25 °C unless otherwise specifi | | | | | | | specified | | |
|---|---|-------------------------|---------|-----------|-----------------------|------------|-----------|------|--|
| Symbol Conditions | | | | min. | typ. | max. | Units | | |
| IGBT | Jonaide | 7110 | | | | ry Pi | maxi | Omio | |
| V _{CEsat} | I _C = 800 A, | T. = 25 (1 | 25) °C | | Ī | 3,3 (4,3) | 3,9 | V | |
| V _{CEO} | $T_i = 25 (12)$ | | _0, 0 | | | , | 2 (2,3) | V | |
| r _{CE} | $T_i = 25 (12)$ | | | | | | 2,4 (3,3) | mΩ | |
| I _{CES} | $V_{GE} = 0 \text{ V}, V_{CE} = V_{CES},$ | | | | | (60) | 4 | mA | |
| CES | T _i = 25 (125) °C | | | | | ` , | | | |
| E _{on} + E _{off} | I _C = 800 A, V _{CC} = 900 V | | | | | 690 | mJ | | |
| 0 | T _i = 125 °C, V _{CC} = 1200 V | | | | | 1017 | mJ | | |
| R _{CC' + EE'} | terminal ch | ip, T _i = 12 | 5 °C | | | 0,13 | | mΩ | |
| L _{CE} | top, bottom | ı , | | | | 3,8 | | nH | |
| C _{CHC} | per phase, | AC-side | | | | 3,2 | | nF | |
| Inverse o | diode | | | | | | | | |
| $V_F = V_{EC}$ | I _F = 800 A, | $T_i = 25 (1$ | 25) °C | | | 2,3 (2,1) | 2,9 | V | |
| V _{TO} | $T_i = 25 (12)$ | 5) °C | | | | 1,3 (1) | 1,6 (1,3) | V | |
| r _T | $T_{j} = 25 (12)$ | | | | | 1,3 (1,4) | 1,6 (1,7) | mΩ | |
| E _{rr} | $I_{\rm C} = 800 \text{A},$ | $V_{CC} = 90$ | 0 V | | | | 85 | mJ | |
| | $T_j = 125 ^{\circ}\text{C}$ | $V_{CC} = 12$ | 200 V | | | | 101 | mJ | |
| Mechani | cal data | | | | | | | | |
| M _{dc} | DC termina | als, SI Unit | s | | 6 | | 8 | Nm | |
| M _{ac} | AC termina | | | | 13 | | 15 | Nm | |
| w | SKiiP® 2 System w/o heat sink | | | | | 3,5 | | kg | |
| w | heat sink | heat sink | | | | 8,5 | | kg | |
| Thermal | characte | ristics (| P16 hea | t sink; 2 | 75m ³ /h); | ", " refer | ence to | | |
| temperat | ture sens | or | | | | • | | | |
| $R_{th(j-s)l}$ | per IGBT | | | | | | 0,02 | K/W | |
| $R_{th(j-s)D}$ | per diode | | | | | | 0,067 | K/W | |
| R _{th(s-a)} | per module |) | | | | | 0,033 | K/W | |
| Z_{th} | R _i (mK/W) (max. values) | | | | tau _i (s) | | | | |
| | 1 | 2 | 3 | 4 | 1 | 2 | 3 | 4 | |
| $Z_{th(j-r)I}$ | 2 | 15 | 2 | 0 | 1 | 0,13 | 0,001 | 1 | |
| $Z_{th(j-r)D}$ | 7 | 51 | 8 | 0 | 1 | 0,13 | 0,001 | 1 | |
| $Z_{\text{th(r-a)}}$ | 1,6 | 22 | 7 | 2,4 | 494 | 165 | 20 | 0,03 | |



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SKiiP 1092GB170-4D



| Absolute Maximum Ratings | | _a = 25 °C unless otherwise specified | | |
|--------------------------|---|---|-------|--|
| Symbol | Conditions | Values | Units | |
| V_{S1} | stabilized 15 V power supply | 18 | V | |
| V_{S2} | unstabilized 24 V power supply | 30 | V | |
| V_{iH} | input signal voltage (high) | 15 + 0,3 | V | |
| dv/dt | secondary to primary side | 75 | kV/μs | |
| V_{isollO} | input / output (AC, r.m.s., 2s) | 4000 | Vac | |
| V _{isol12} | output 1 / output 2 (AC, r.m.s., 2s) | 1500 | Vac | |
| f _{sw} | switching frequency | 7 | kHz | |
| f _{out} | output frequency for I=I _C ;sin. | 1 | kHz | |
| $T_{op} (T_{stg})$ | operating / storage temperature | - 40 + 85 | °C | |

2-pack - integrated intelligent Power System

2-pack integrated gate driver

SKiiP 1092GB170-4D

Gate driver features

- CMOS compatible inputs
- Wide range power supply
- Integrated circuitry to sense phase current, heat sink temperature and DC-bus voltage (option)
- · Short circuit protection
- Over current protection
- Over voltage protection (option)
- Power supply protected against under voltage
- · Interlock of top/bottom switch
- Isolation by transformers
- Fibre optic interface (option for GB-types only)
- IEC 60068-1 (climate) 25/85/56

| Characte | eristics | $(T_a = 25 °C)$ | | | = 25 °C) |
|------------------------|--|-----------------|---|------|----------|
| Symbol | Conditions | min. | typ. | max. | Units |
| V _{S1} | supply voltage stabilized | 14,4 | 15 | 15,6 | V |
| V_{S2} | supply voltage non stabilized | 20 | 24 | 30 | V |
| I _{S1} | V _{S1} = 15 V | 290+590 | 290+590*f/f _{max} +1,2*(I _{AC} /A) | | |
| I _{S2} | V _{S2} = 24 V | 220+430 | 220+430*f/f _{max} +0,85*(I _{AC} /A) | | |
| V _{iT+} | input threshold voltage (High) | | | 12,3 | V |
| V_{iT-} | input threshold voltage (Low) | 4,6 | | | V |
| R _{IN} | input resistance | 10 | | | kΩ |
| $t_{d(on)IO}$ | input-output turn-on propagation time | | | 1,5 | μs |
| t _{d(off)IO} | input-output turn-off propagation time | | | 1,4 | μs |
| tpERRRESET | error memory reset time | 9 | | | μs |
| t _{TD} | top / bottom switch : interlock time | | 3,3 | | μs |
| I _{analogOUT} | 8 V corresponds to max. current of 15 V supply voltage | | 1000 | | |
| I _{Vs1outmax} | (available when supplied with 24 V) | | | 50 | mA |
| I _{A0max} | output current at pin 12/14 | | | 5 | mA |
| V _{0I} | logic low output voltage | | | 0,6 | V |
| V _{0H} | logic high output voltage | | | 30 | V |
| I _{TRIPSC} | over current trip level (I _{analog OUT} = 10 V) | | 1250 | | Α |
| I _{TRIPLG} | ground fault protection | | | | Α |
| T_tp | over temperature protection | 110 | | 120 | °C |
| U _{DCTRIP} | trip level of U _{DC} -protection | 1200 | | | V |
| | (U _{analog OUT} = 9 V); (option) | | | | |

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